











TPD2E007 SLVS796I - SEPTEMBER 2008-REVISED MARCH 2016

TPD2E007 2-Channel ESD Protection Array for AC-Coupled/Negative-Rail Data Interfaces

Features

- IEC 61000-4-2 Level 4 ESD Protection
 - ±8-kV IEC 61000-4-2 Contact Discharge
 - ±15-kV IEC 61000-4-2 Air-Gap Discharge
- IEC 61000-4-5 Surge Protection
 - 4.5-A Peak Pulse Current (8/20-µs Pulse)
- IO Capacitance 15 pF (Max)
- Low 50-nA Leakage Current
- Space-Saving PicoStar[™] and SOT Package

Applications

- Cell Phones
- **Audio Interface Connections**
- Consumer Electronics (DVR, Set-Top Box, TV)
- Industrial Interfaces (RS-232, RS-485, RS-422, LVDS)

3 Description

This device is a transient voltage suppressor (TVS) based electrostatic discharge (ESD) protection device designed to offer system level ESD solutions for wide range of portable and industrial applications. The back-to-back diode array allows AC-coupled or negative-going data transmission (audio interface, LVDS, RS-485, RS-232, and so forth) without compromising signal integrity. This device exceeds the IEC 61000-4-2 (Level 4) ESD protection and is ideal for providing system level ESD protection for the internal ICs when placed near the connector.

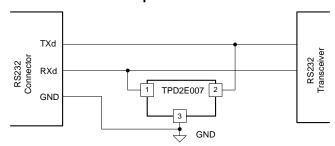
The TPD2E007 is offered in a 4-bump PicoStar and 3-pin SOT (DGK) packages. The PicoStar package (YFM), with only 0.15 mm (Max) package height, is recommended for ultra space saving application where the package height is a key concern. The PicoStar package can be used in either embedded PCB board applications or in surface mount applications. The industry standard SOT package offers straightforward board layout option in legacy designs.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TDD0E007	SOT (3)	2.00 mm x 1.25 mm
TPD2E007	PicoStar (4)	0.77 mm x 0.77 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Example Schematic



Equivalent Schematic Representation

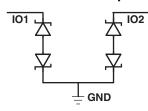




Table of Contents

1	Features 1	7.3 Feature Description	6
2	Applications 1	7.4 Device Functional Modes	6
3	Description 1	8 Application and Implementation	<mark>7</mark>
4	Revision History2	8.1 Application Information	<mark>7</mark>
5	Pin Configuration and Functions3	8.2 Typical Application	<mark>7</mark>
6	Specifications4	9 Power Supply Recommendations	8
•	6.1 Absolute Maximum Ratings 4	10 Layout	8
	6.2 ESD Ratings 4	10.1 Layout Guidelines	8
	6.3 ESD Ratings: Surge Protection	10.2 Layout Example	8
	6.4 Recommended Operating Conditions	11 Device and Documentation Support	9
	6.5 Thermal Information	11.1 Community Resources	9
	6.6 Electrical Characteristics	11.2 Trademarks	9
	6.7 Typical Characteristics	11.3 Electrostatic Discharge Caution	9
7	Detailed Description 6	11.4 Glossary	9
•	7.1 Overview 6	12 Mechanical, Packaging, and Orderable	
	7.2 Functional Block Diagram 6	Information	9

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision H (January 2016) to Revision I	Page
•	Made changes to ESDS section	1
С	hanges from Revision G (December 2015) to Revision H	Page
•	Updated the break-down voltage for clarity	5
С	hanges from Revision F (August 2014) to Revision G	Page
•	Updated the Handling Ratings table to an ESD Ratings table and moved T _{stg} to the Absolute Maximum Ratings table	4
•	Added $f = 10$ MHz to the Channel input capacitance test condition in the Electrical Characteristics table	5
•	Added Community Resources	9
С	hanges from Revision E (August 2010) to Revision F	Page
•	Added Pin Configuration and Functions section, Handling Rating table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout	

Changes from Revision D (October 2009) to Revision E

Page

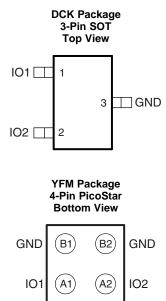
Added max continuous power dissipation value for DCK package......4

section ______1

section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information



5 Pin Configuration and Functions



 $0.8 \text{ mm} \times 0.8 \text{ mm} (0.4 \text{ mm pitch})$

Pin Functions

	PIN				
NAME	DCK NO.	YFM NO.	I/O	DESCRIPTION	
GND	3	B1, B2	G	Ground	
IO1	1	A1	Ю	ESD protected channel	
IO2	2	A2	Ю	ESD protected channel	



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT	
V_{IO}			-13.5	13.5	V	
	Continuous power dissipation	YFM package		270	\^/	
	$(T_A = 70^{\circ}C)$	DCK package		218	mW	
	Operating temperature		-40	85	°C	
TJ	Junction temperature			150	°C	
	Dump tomporature (coldering)	Infrared (15 s)		220	°C	
	Bump temperature (soldering)	Vapor phase (60 s)		215		
	Lead temperature (soldering, 10 s)			300	°C	
T _{stg}	Storage temperature		-65	150	°C	

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
\/	Electrostatic	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)		\/
V _(ESD)	discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±1500	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 ESD Ratings: Surge Protection

				VALUE	UNIT	
, Electrostatic	IEC 61000-4-2 ESD ratings	Contact	±8000	W		
V (I	^{ESD)} discharge	TEC 61000-4-2 ESD fattings	Air gap	±15000	V	

6.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
V_{IO}	Operating voltage	-13	13	V
	Operating temperature	-40	85	°C

6.5 Thermal Information

		TP	TPD2E007			
	THERMAL METRIC ⁽¹⁾	DCK (SOT)	YFM (PicoStar)	UNIT		
		3 PINS	4 PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	251.9	175.9	°C/W		
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	115.4	39.2	°C/W		
$R_{\theta JB}$	Junction-to-board thermal resistance	42.4	28.7	°C/W		
ΨЈТ	Junction-to-top characterization parameter	9.4	8.3	°C/W		
Ψ_{JB}	Junction-to-board characterization parameter	42.2	28.7	°C/W		
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W		

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.6 Electrical Characteristics

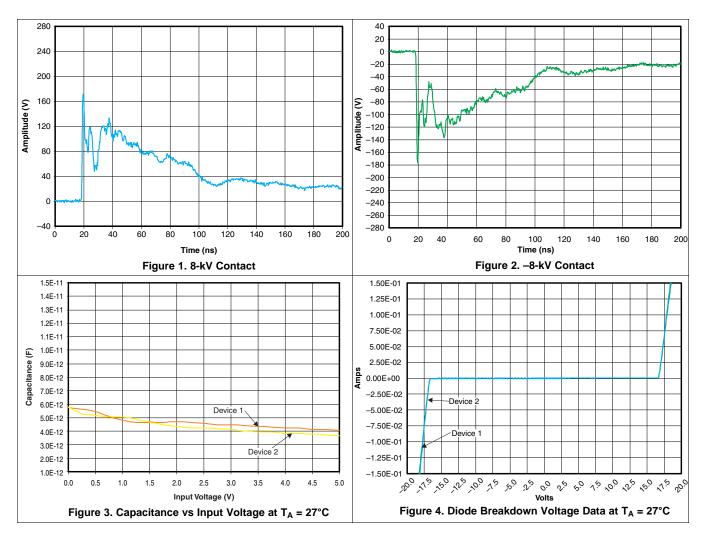
 $T_A = -40$ °C to 85°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V_{BRF}	Break-down voltage, pin 1 or 2 to GND	I _{IO} = 10 mA	14			V
V_{BRR}	Break-down voltage, GND to pin 1 or 2	I _{IO} = 10 mA	14			V
I _{IO}	Channel leakage current			20	50	nA
R _d	Dynamic resistance			3.5		Ω
C _{IN}	Channel input capacitance	$V_{IO} = 2.5 \text{ V}; f = 10 \text{ MHz}$		10	15	pF

⁽¹⁾ Typical values are at $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

6.7 Typical Characteristics

IEC Clamping Waveforms (20 ns/div)





7 Detailed Description

7.1 Overview

The TPD2E007 an ESD protection device designed to offer system level ESD solutions for wide range of portable and industrial applications. The back-to-back diode array allows AC-coupled or negative-going data transmission (audio interface, LVDS, RS-485, RS-232, etc.) without compromising signal integrity. The PicoStar package is intended to be embedded inside the printed circuit board which saves board space in portable applications. This device exceeds the IEC 61000-4-2 (Level 4) ESD protection and is ideal for providing system level ESD protection for the internal ICs when placed near the connector.

7.2 Functional Block Diagram

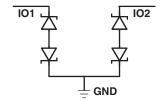


Figure 5. Equivalent Schematic Representation

7.3 Feature Description

The TPD2E007 an ESD protection device designed to offer system level ESD solutions for wide range of portable and industrial applications. The back-to-back diode array allows AC-coupled or negative-going data transmission (audio interface, LVDS, RS-485, RS-232, etc.) without compromising signal integrity. The PicoStar package is intended to be embedded inside the printed circuit board which saves board space in portable applications. This device exceeds the IEC 61000-4-2 (Level 4) ESD protection and is ideal for providing system level ESD protection for the internal ICs when placed near the connector.

7.3.1 IEC 61000-4-2 Level 4 ESD Protection

The I/O pins can withstand ESD events up to ±12-kV contact and ±15 kV-air. An ESD/surge clamp diverts the current to ground.

7.3.2 IEC 61000-4-5 Surge Protection

The I/O pins can withstand surge events up to 4.5 A (8/20 µs waveform). An ESD/surge clamp diverts this current to ground.

7.3.3 IO Capacitance

The capacitance between each I/O pin to ground is 15 pF.

7.3.4 Low 50-nA Leakage Current

The I/O pins feature a low 50-nA (max) leakage current.

7.3.5 Space-Saving PicoStar and SOT Package

This device is offered in both a space-saving PicoStar package, as well as a standard DCK package.

7.4 Device Functional Modes

TPD2E007 is a passive integrated circuit that triggers when voltages are above or below V_{BR} . During ESD events, voltages as high as ± 15 kV (air) can be directed to ground via the internal diode network. Once the voltages on the protected line fall below the trigger levels of TPD2E007 (usually within 10's of nano-seconds) the device reverts to passive.



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

TPD2E007 is a diode type TVS which is typically used to provide a path to ground for dissipating ESD events on signal lines between a human interface connector and a system. As the current from ESD passes through the TVS, only a small voltage drop is present across the diode. This is the voltage presented to the protected IC.

8.2 Typical Application

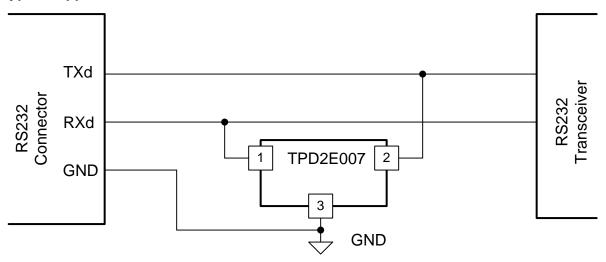


Figure 6. Example Schematic

8.2.1 Design Requirements

For this design example, a single TPD2E007 is used to protect an RS232 3-wire connector.

Given the application, the following parameters are known.

Table 1. Design Parameters

DESIGN PARAMETER	VALUE
Signal range on all pins except GND	–12 V to 12 V
Surge Withstand - IEC 61000-4-5	150 W

8.2.2 Detailed Design Procedure

To begin the design process, some parameters must be decided upon; the designer needs to know the following:

- Signal voltage range on all protected lines
- Surge Withstand

8.2.2.1 Signal Range on IO1 and IO2 Pins

The TPD2E007 has 2 IO pins which can support up to ±13 V.

8.2.2.2 Surge Withstand

The TPD2E007 can withstand up to 170W of IEC 61000-4-5 8/20-µs surge.

8.2.3 Application Curve

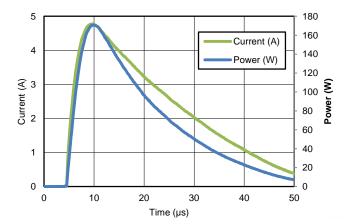


Figure 7. Surge Pulse Waveform

9 Power Supply Recommendations

This device is a passive ESD device so there is no need to power it. Take care not to violate the recommended I/O specification (±13 V) to ensure the device functions properly.

10 Layout

10.1 Layout Guidelines

- The optimum placement is as close to the connector as possible.
 - EMI during an ESD event can couple from the trace being struck to other nearby unprotected traces, resulting in early system failures.
 - The PCB designer needs to minimize the possibility of EMI coupling by keeping any unprotected traces away from the protected traces which are between the TVS and the connector.
- Route the protected traces as straight as possible.
- Eliminate any sharp corners on the protected traces between the TVS and the connector by using rounded corners with the largest radii possible.
 - Electric fields tend to build up on corners, increasing EMI coupling.

10.2 Layout Example

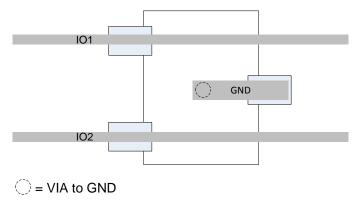


Figure 8. Layout Recommendation



11 Device and Documentation Support

11.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.2 Trademarks

PicoStar, E2E are trademarks of Texas Instruments.

All other trademarks are the property of their respective owners.

11.3 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 14-May-2025

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TPD2E007DCKR	Active	Production	SC70 (DCK) 3	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	45U
TPD2E007DCKR.Z	Active	Production	SC70 (DCK) 3	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	45U
TPD2E007YFMTG4	Obsolete	Production	DSLGA (YFM) 4	-	-	Call TI	Call TI	-40 to 85	

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

www.ti.com 20-Apr-2024

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPD2E007DCKR	SC70	DCK	3	3000	179.0	8.4	2.4	2.4	1.19	4.0	8.0	Q3

PACKAGE MATERIALS INFORMATION

www.ti.com 20-Apr-2024

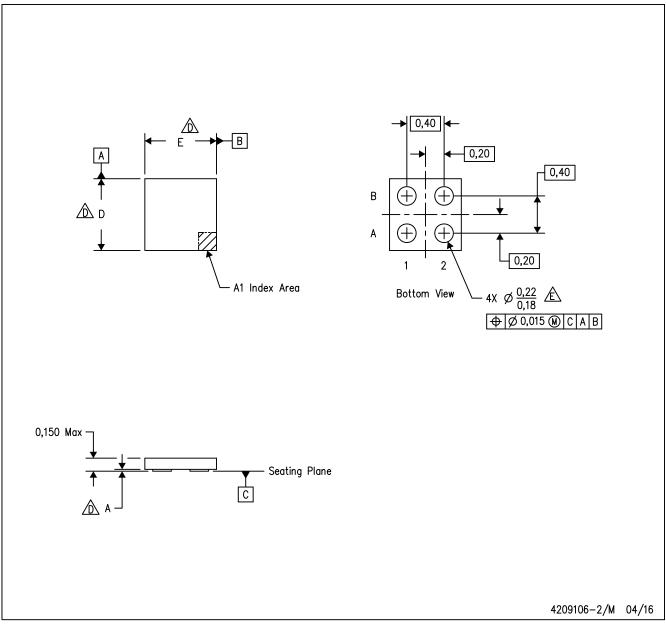


*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	TPD2E007DCKR	SC70	DCK	3	3000	213.0	191.0	35.0	

YFM (S-pSTAR-N4)

PicoStar™



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
- B. This drawing is subject to change without notice.
- C. PicoStar™ package configuration.

The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative.

Reference Product Data Sheet for array population. 2 x 2 matrix pattern is shown for illustration only.

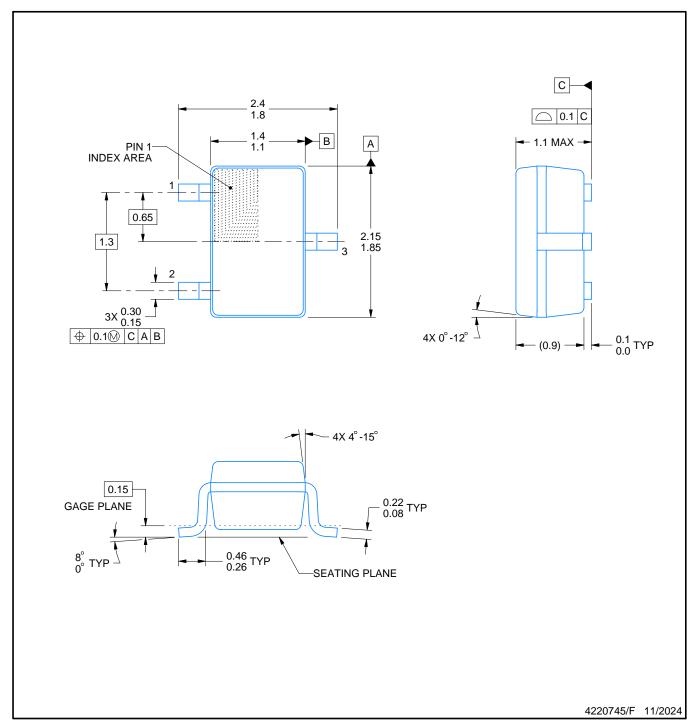
F. This package is a Pb-free solder land design.

PicoStar is a trademark of Texas Instruments.





SMALL OUTLINE TRANSISTOR SC70



NOTES:

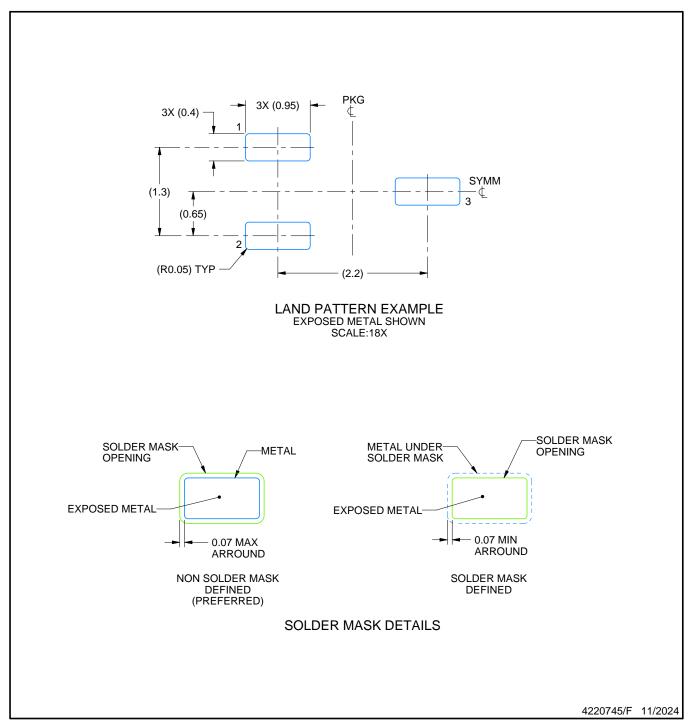
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed
- 0.25mm per side



SMALL OUTLINE TRANSISTOR SC70

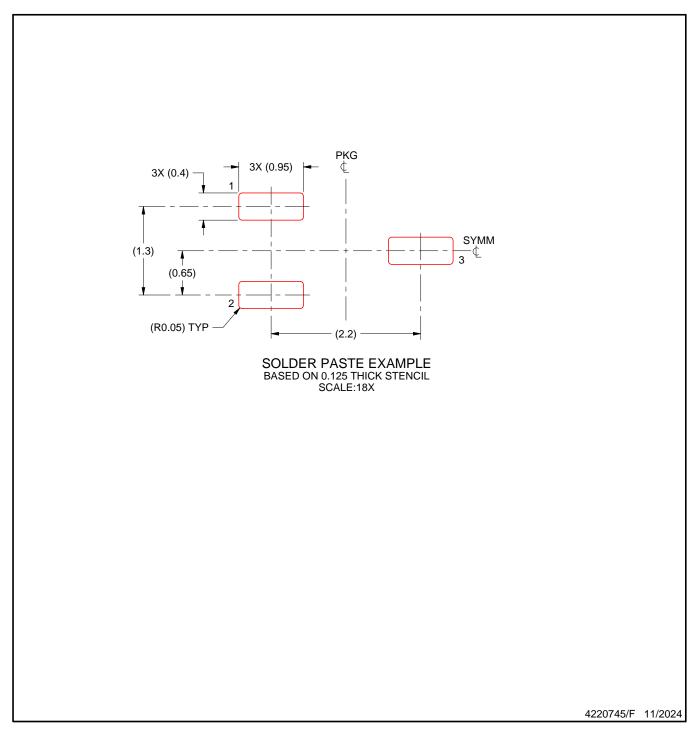


NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR SC70



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.



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